Adaptive Phenotypic Plasticity of Siberian Elm in Response to Drought Stress: Increased Stomatal Pore Depth

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Abstract: Leaf stomatal characteristics of Siberian elm (Ulmus pumila) were investigated by electron microscopy and white light scanning interferometry. On the basis of average annual precipitations, two types of tree specimens were collected from Korea, China, and Mongolia: (1) trees under normal environmental conditions and (2) trees under arid conditions. Field emission scanning electron microscopy revealed oval-shaped stomata on the lower surface, and they were ca. 20 μm in width. In-lens secondary electron imaging showed differences in electron density and stomatal pore depth between the two types. According to the line profile analysis by white light scanning interferometry, stomata under arid conditions appeared to have higher levels of the stomatal pore depth than ones under normal conditions. Focused ion beam–field emission electron microscopy supported the increased stomatal pore depth with the increasing drought stress gradient. These results suggest that complementary microscopy can be employed to unravel the adaptive phenotypic plasticity of Siberian elm in response to drought stress.

Key words: drought, FIB, interferometry, stomata, Ulmus pumila

INTRODUCTION

Stoma (pl. stomata) is an opening or pore in the epidermis bordered by guard cells in plants (Evert, 2006). Stoma commonly includes both the pore and guard cells; stomatal complex refers to the stoma and any specialized epidermal cells adjacent to it (Mauseth, 1988; Carpenter, 2005). The main control of gas exchange and water movement in plants is provided by stomata (Cutler et al., 2008). Variations of stomatal structural characteristics are thought to affect gas exchange and the water pathways in the leaf (Roth-Nebelsick, 2007). The species’ ability to respond and adapt to changing environments is critical for their survival and distribution.

Elms are deciduous trees belonging to the genus Ulmus in the northern hemisphere. Ulmus pumila L., commonly called Siberian elm, is a fast-growing and small- to medium-sized tree widely distributed in Korea, China, and Mongolia [Illinois Nature Preserves Commission (INPC), 1990]. The trees have been preferentially planted in Mongolia as main broadleaved species for the rehabilitation of arid areas (Shi et al., 2004; Valladares & Sánchez-Gómez, 2006). Investigating stomatal characteristics of species tolerant to drought stress would provide a better understanding of tree adaptations in harsh environment.

Although field emission scanning electron microscopy (FESEM) provides a high-resolution image of stomatal complexes, accurate measurement of the z-axis dimension is limited because of the imaging principles. White light scanning interferometry (WLSI) has been used to provide three-dimensional metrology of plant leaves (Kim et al., 2010). In addition, focused ion beam (FIB) systems have been increasingly used for biological materials, as well as metals and semiconductors (Hou & Yao, 2007). Combining the FIB’s precise machining abilities with the FESEM’s high-resolution imaging abilities, the two-beam system (FIB-FESEM) leads to novel applications (Yao, 2007). Here we report the morphological response of Siberian elm under different levels of drought stress, and provide an experimental evidence on the quantitative analysis of the vertical profiles of leaf stomata.

MATERIALS AND METHODS

Plant Materials
Leaves of U. pumila were collected from ca. 60-year-old field-grown trees in four sites: (i) Jeongseon, Korea (JS), (ii) Qingyuan, China (QI), (iii) Kokunhang, Mongolia (KK), and (iv) Wulanaodou, China (WU). The trees were subjected to different levels of water supply conditions during their growing seasons over the past decades. On the basis of average annual precipitations, they were classified into two categories: (i) normal conditions [JS (1,316 mm) and QI (634 mm)] and (ii) arid conditions [KK (235 mm) and WU (262 mm)]. Leaves were taken from the middle part of the crown that was exposed to full sunlight throughout the day.
FESEM
Leaf fragments were mounted on a stub and sputter-coated with platinum (Pt) using a coater and examined by FESEM (Supra 55VP; Carl Zeiss, Oberkochen, Germany) at 2 kV. An annular-type in-lens detector was used to acquire secondary electron signals. Stomatal dimensions were measured using a software package.

WLSI
Optical scanning interferometry was performed for the quantitative analysis of stomatal complexes (NanoView-E1000; NanoSystem, Daejeon, Korea). Line profile analysis was conducted to measure the stomatal pore depth (from epidermis to pore) of 30 stomatal complexes (Kim et al., 2011). The mean value of stomatal pore depth was compared among sites by Duncan’s multiple range test.

FIB-FESEM
The Pt-coated leaf specimens were mounted on FIB-FESEM (Auriga; Carl Zeiss). Coarse cross-sections of stomatal complexes were made with a 10-nA ion beam current and fine-polished with a 50-pA ion beam current. An in-column energy-selective backscattered electron (EsB) detector provided the exposed surface image (Kim & Jaksch, 2009). The stomatal pore depth was measured from 20 stomatal complexes and analyzed as described above.

RESULTS

FESEM
Stomata were present only on the lower leaf surface, oval-shaped, and ca. 20 μm in width (Fig. 1). No significant differences in stomatal morphology were observed between leaves under normal conditions (Figs. 1a, 1b). The electron-dense stomatal pores commonly observed on the leaf surface under arid conditions (Figs. 1c, 1d) appeared to be more deeply located relative to the epidermis than those under normal conditions.

WLSI
Surface topography of leaves was revealed in scan areas (Fig. 2a). Surface fluctuations in height profiles were evident by the color scale (Fig. 2b), and the pore regions in the center were demarcated from the outer stomatal chamber. An arbitrary line profile analysis allowed for the measurement of the stomatal pore depth (Fig. 2c). The leaves under arid conditions had a higher stomatal pore depth (ca. 3.0 μm) than those under normal conditions (ca. 1.8 μm).
Based on the vertical planes of stomatal complexes, it was obvious that the depth difference between the leaf epidermis and pore increased under arid conditions. 

Significantly different levels of stomatal pore depth were found between leaves from the normal conditions and arid conditions, ca. 3 μm and ca. 5 μm, respectively (Fig. 4). No significant differences were found in stomatal pore depth within the same groups (p = 0.05).

**DISCUSSION**

This study provided an experimental evidence for the adaptive response of leaf stomata to drought stress in Siberian elm. It was found that naturally reducing water supply in the forest stand caused an alteration of stomatal architecture of Siberian elm. The most striking differences between stomata were found in the pore position of stomatal complexes. Stomata under arid conditions were mainly characterized by the more sunken stomatal pores. Qualitative features of sunken stomatal pores were visualized by FESEM where a coaxial in-lens imaging provided a clue to further address the differences between stomata from the leaves of the environments.

In addition, quantitative aspects of stomatal architecture were analyzed by WLSI and FIB-FESEM. Although Pt-coated leaves for FESEM were scanned for WLSI in this study, even the light reflection from uncoated raw leaf materials was sufficient to generate three-dimensional surface plots (Kim et al., 2011). The measurements of stomatal pore depth by WLSI may reflect the drought stress gradients.

The FIB-FESEM was effective to expose the vertical profiles of leaf surface with indiscernible beam damage. EsB imaging was sufficient to resolve the vertical profiles of leaf surface, based on the compositional contrast. The increase in stomatal pore depth measured by FIB-FESEM was in agreement with the drought stress gradient of the sites.
Differences in stomatal pore depth between WLSI and FIB-FESEM might be attributed to several factors including specimen orientation and spatial resolution of beam source.

Plants exposed to continued arid conditions tend to improve water use efficiency by minimizing water loss. It is natural that stomata under arid conditions have sunken stomatal pores (Cutler et al., 2008). Such architectural characteristics, owing to their boundary layer conductance, may contribute to the shielding of stomata from the drying winds in arid areas, and keep the stomata less vulnerable to water loss than other stomata types. To our knowledge, this is the first report on the use of complementary microscopy to unravel the stomatal response to drought stress in plants.

In summary, our findings indicate that stomatal architecture is plastic to drought stress in Siberian elm. The stomatal pore positions can be altered to maintain the water use efficiency to survive under adverse conditions. Increased stomatal pore depth is regarded as a morphological response to drought stress, which could be quantified by microscopy. Elucidation of triggering factors and thresholds of environmental pressure for stomatal modifications will enhance our understanding of the nature of tree responses to drought stress.

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**REFERENCES**


Figure 4. Stomatal pore depth. Significantly different levels of depth were found between leaves under different environments. JS, Jeongseon; QI, Qingyuan; KK, Kokunhang; WU, Wulanaodu.

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